## GNPGraystar

TECHNICAL DATA SHEET
Beta Silicon Carbide ( $\beta$-SiC)

Typical Chemistry

| Silicon Carbide (SiC) |  | 97-99.99\% |
| :---: | :---: | :---: |
| Free Carbon (C) |  | 0-0.30\% |
| Silicon Dioxide ( $\mathrm{SiO}_{2}$ ) |  | 0-1.20\% |
| Free Silicon (Si) |  | 0-0.20\% |
| Iron $\left(\mathrm{Fe}_{2} \mathrm{O}_{3}\right)$ |  | 0-0.30\% |
| Aluminum Oxide $\left(\mathrm{Al}_{2} \mathrm{O}_{3}\right)$ |  | < $0.03 \%$ |
| Magnesium Oxide (MgO) |  | < $0.03 \%$ |
| Calcium Oxide (CaO) |  | < $0.03 \%$ |
| * Can be processed according to customer requirements |  |  |
| Physical Characteristics |  |  |
| Crystal Form: | Cubic (Beta SiC) |  |
| True Density: | $3.21 \mathrm{~g} / \mathrm{cm}^{3}$ |  |
| Melting Point: | Dissociates at Approx. $2500^{\circ} \mathrm{C}$ |  |
| Hardness: | Mohs: 9.5-9.75 |  |

## Available Sizes (Microns) - via Malvern

| Size | D10 | D50 | D90 | D100 | Tap Density <br> $\left(\mathrm{g} / \mathrm{cm}^{3}\right)$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| W0.5 | $0.3 \pm 0.1$ | $0.6 \pm 0.1$ | $1.4 \pm 0.3$ | $\leq 3$ | $0.9 \pm 0.05$ |
| W1 | $0.4 \pm 0.2$ | $1 \pm 0.25$ | $2.5 \pm 0.2$ | $\leq 5$ | $0.87 \pm 0.05$ |
| W1.5 | $0.6 \pm 0.2$ | $1.5 \pm 0.2$ | $2.6 \pm 0.4$ | $\leq 5$ | $0.88 \pm 0.05$ |
| W2.5 | $1.35 \pm 0.3$ | $2.5 \pm 0.2$ | $3.82 \pm 0.5$ | $\leq 6$ | $1.30 \pm 0.05$ |
| W3.5 | $1.94 \pm 0.3$ | $3.5 \pm 0.2$ | $5.8 \pm 0.5$ | $\leq 7.64$ | $1.44 \pm 0.05$ |
| W5 | $2.8 \pm 0.4$ | $4.5 \pm 0.4$ | $7.15 \pm 0.45$ | $\leq 11.2$ | $1.63 \pm 0.05$ |
| W7 | $4.1 \pm 0.15$ | $6.5 \pm 0.3$ | $10.3 \pm 0.8$ | $\leq 15$ | $1.64 \pm 0.05$ |
| W10 | $6.6 \pm 0.5$ | $9.7 \pm 0.8$ | $15.0 \pm 3.0$ | $\leq 21.2$ | $1.70 \pm 0.05$ |
| W14 | $8.35 \pm 0.35$ | $12.7 \pm 1.2$ | $18.9 \pm 2.6$ | $\leq 24.1$ | $1.72 \pm 0.05$ |
| W20 | $11.7 \pm 0.7$ | $18.4 \pm 1.6$ | $28.5 \pm 3.1$ | $\leq 40.1$ | $1.75 \pm 0.05$ |
| W28 | $16.0 \pm 0.7$ | $23.5 \pm 1.0$ | $34.5 \pm 2.7$ | $\leq 51.8$ | $1.80 \pm 0.05$ |
| W40 | $23.4 \pm 0.3$ | $35.8 \pm 1.6$ | $54.4 \pm 3.9$ | $\leq 76.0$ | $1.85 \pm 0.05$ |

## Northern Office

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## Description:

GNPGraystar's Beta Silicon Carbide is a synthetic SiC with a cubic structure, like diamond, which gives it superior physical and chemical properties. Its Mohs hardness is second only to diamond's 10 on the Mohs scale.

In addition to high hardness, $\beta$-SiC has good chemical stability, high thermal conductivity, low thermal expansion, wide band gap, high electro drift velocity, high electronic mobility, and special resistance temperature characteristics.

Therefore, it has superior abrasion resistance, high temperature resistance, thermal shock resistance, radiation resistance, and semiconductive properties

## Applications:

GNPGraystar's $\beta$-SiC is used in applications such as electronics, information technology, precision machining, military and aerospace, high-grade refractories, special ceramic materials, high-grade grinding materials, and reinforcing materials.

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